



FJ4B01110L

Single P-channel MOS FET

For Load switching circuits

Features

- Drain-source ON resistance: $R_{ds(on)}$ typ. = 141 m Ω ($V_{GS} = -2.5$ V)
- CSP (Chip Size Package)
- RoHS compliant (EU RoHS / MSL:Level 1 compliant)

Marking Symbol: 1E

Packaging

Embossed type (Thermo-compression sealing) : 20 000 pcs / reel (standard)

Absolute Maximum Ratings $T_a = 25$ °C

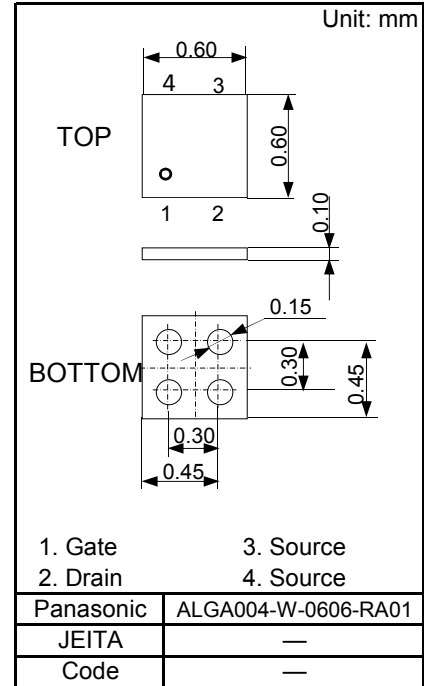
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	VDS	-12	V
Gate-Source Voltage	VGS	± 8	V
Drain Current	ID1 ^{*1}	-1.4	A
	ID2 ^{*2}	-2.2	
	ID3 ^{*3}	-2.6	
Peak Drain Current	IDp1 ^{*1*4}	-11	A
	IDp2 ^{*2*4}	-17	
	IDp3 ^{*3*4}	-20	
Power Dissipation	PD1 ^{*1}	0.34	W
	PD2 ^{*2}	0.76	
	PD3 ^{*3}	1.1	
Channel Temperature	Tch	150	°C
Operating Ambient Temperature	Topr	-40 ~ +85	°C
Storage Temperature	Tstg	-55 ~ +150	°C

Note *1 FR4 board (25.4mm×25.4mm×t1.0mm), Min Cu 36mm² Copper

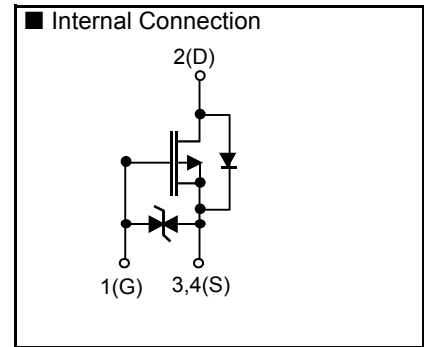
*2 FR4 board (25.4mm×25.4mm×t1.0mm), Full Cu

*3 Ceramic substrate (70mm×70mm×t1.0mm)

*4 t = 10 μ s, Duty Cycle < 1%



Internal Connection





■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	VDSS	ID = -1 mA, VGS = 0	-12			V
Zero Gate Voltage Drain Current	IDSS	VDS = -12 V, VGS = 0			-10	μA
Gate-Source Leakage Current	IGSS	VGS = ±8 V, VDS = 0 V			±10	μA
Gate Threshold Voltage	Vth	ID = -0.598 mA, VDS = -10 V	-0.3		-1.0	V
Drain-Source ON Resistance	RDS(on)	ID = -0.7 A, VGS = -4.5 V		118	153	mΩ
		ID = -0.7 A, VGS = -2.5 V		141	183	
		ID = -0.2 A, VGS = -1.8 V		169	287	
		ID = -0.1 A, VGS = -1.5 V		199	597	
Input Capacitance ^{*1}	Ciss	VDS = -10 V		226		pF
Output Capacitance ^{*1}	Coss	VGS = 0		62		
Reverse Transfer Capacitance ^{*1}	Crss	f = 1MHz		51		
Turn-on delay time ^{*1,*2}	td(on)	VDD = -6 V VGS = 0 to -4.5 V ID = -1.0 A		3.8		
Rise time ^{*1,*2}	tr			2.5		
Turn-off delay time ^{*1,*2}	td(off)			30		
Fall time ^{*1,*2}	tf			5.4		
Total Gate Charge ^{*1}	Qg	VDD = -6 V		3.3		nC
Gate to Source Charge ^{*1}	Qgs	VGS = -4.5 V		0.55		nC
Gate to Drain Miller Charge ^{*1}	Qgd	ID = -1.0 A		0.65		nC
Body Diode Forward Voltage	VF(D-S)	IF = -0.2A, VGS = 0V		-0.7	-1.2	V

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

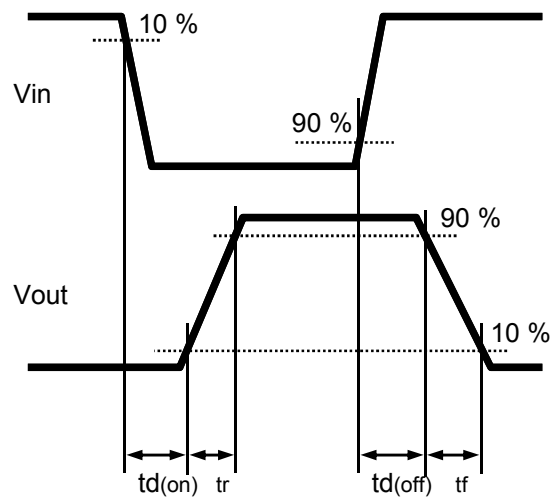
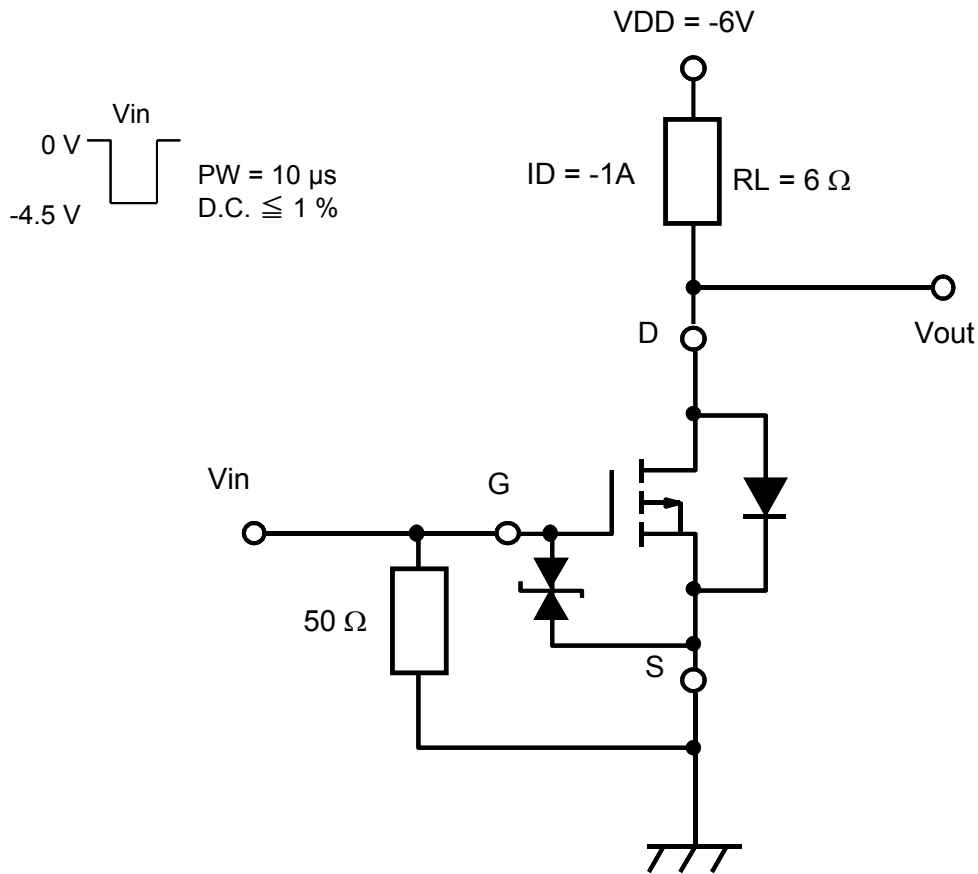
*1 Guaranteed by design, not subject to production testing

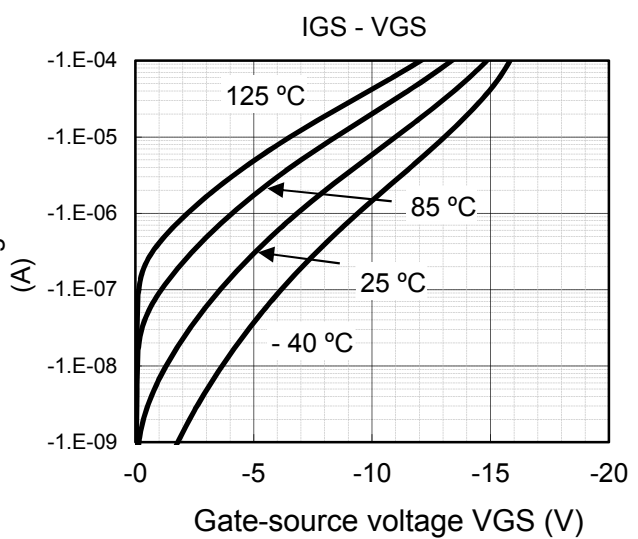
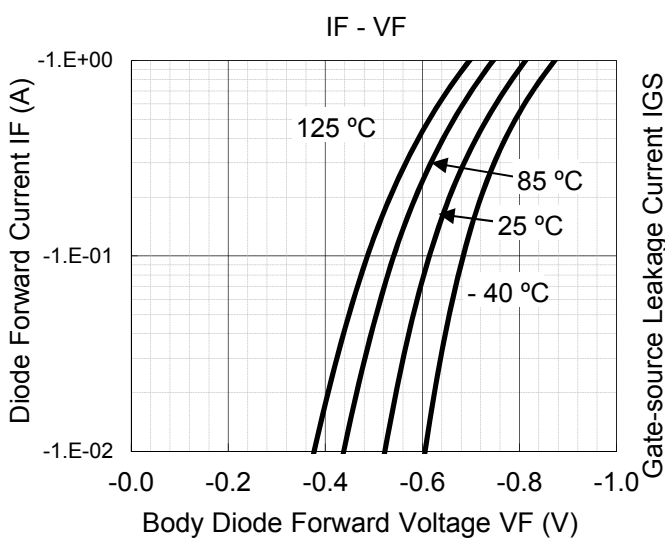
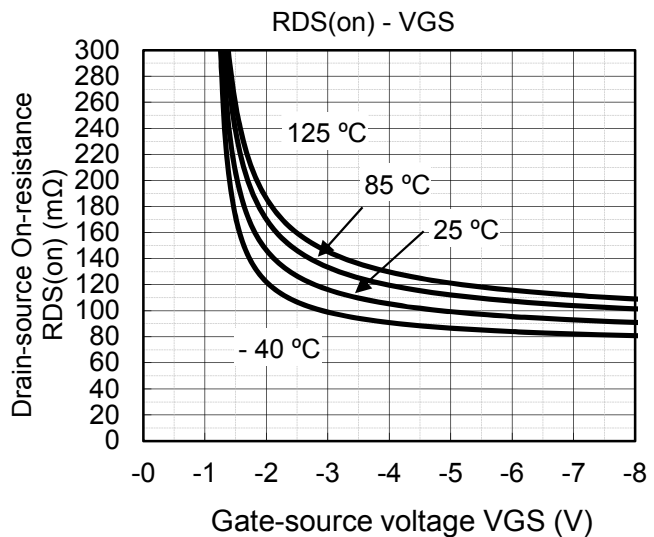
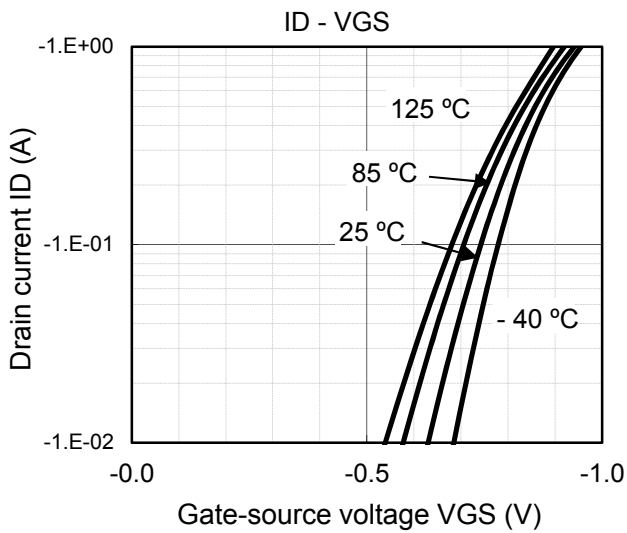
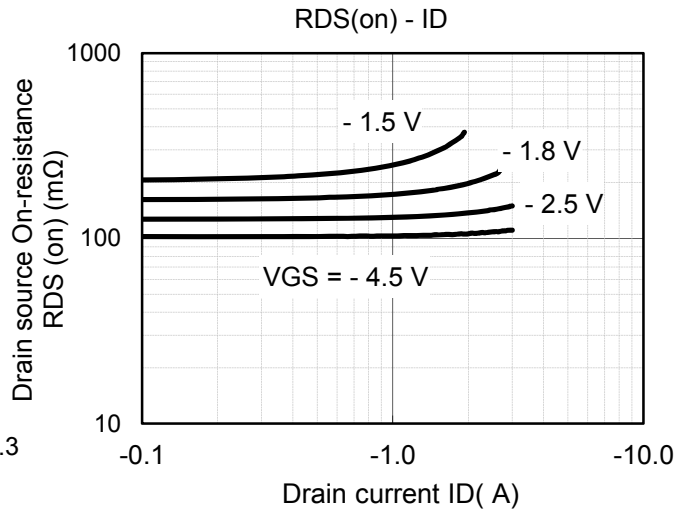
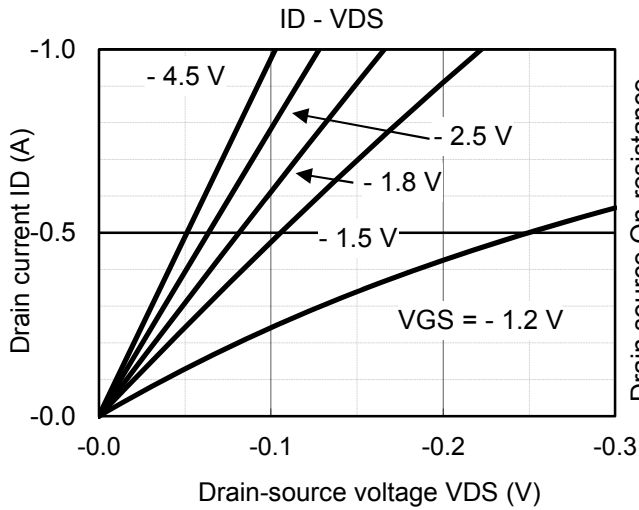
*2 Measurement circuit for Turn-on delay time / Rise time / Turn-off delay time / Fall time

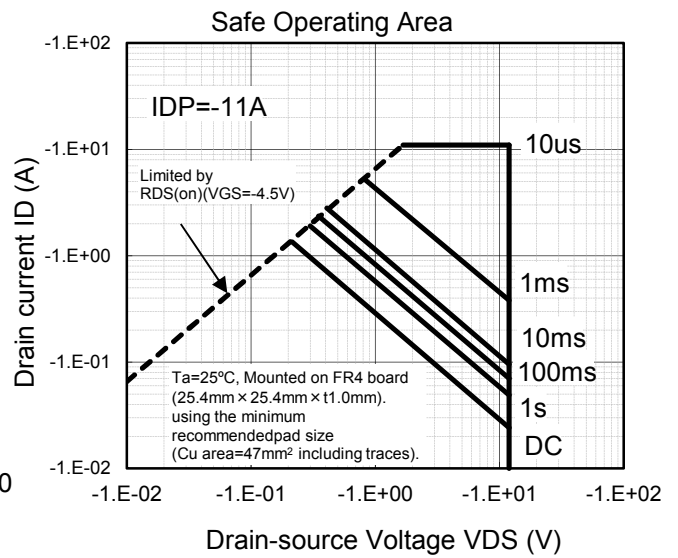
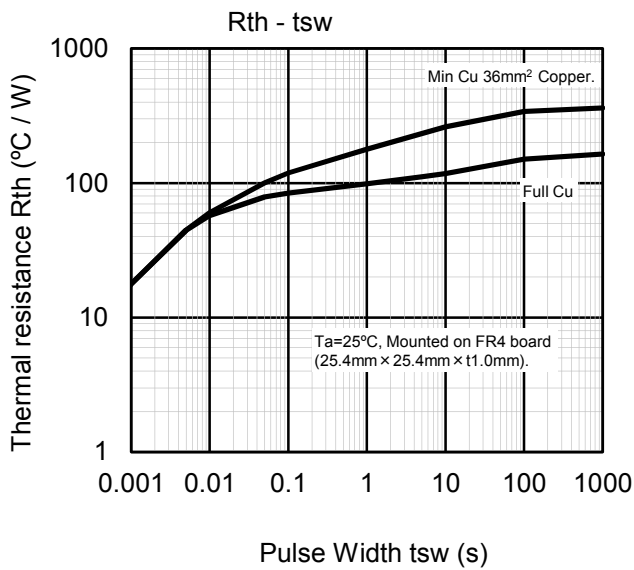
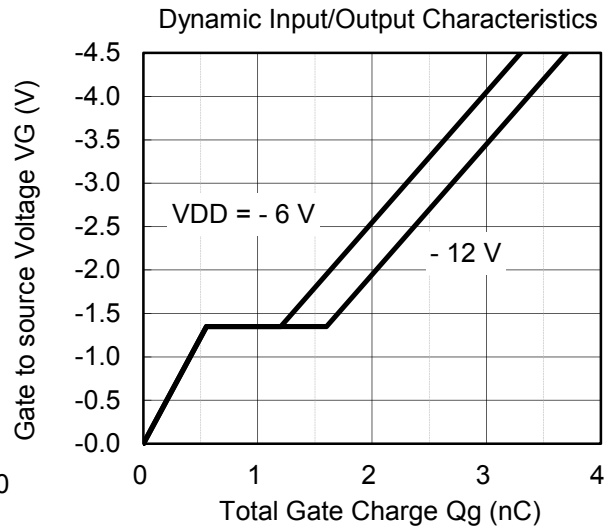
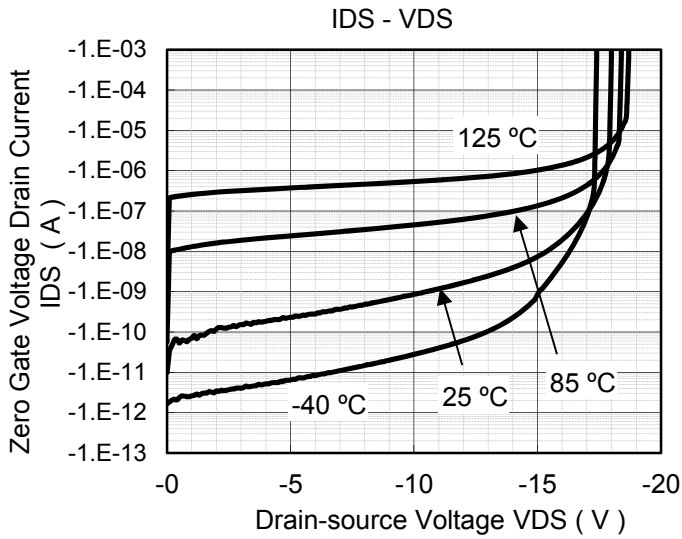
■ Electrical State Discharge Characteristics

Standard	Test Type	Symbol	Conditions	Class	Value	Unit
AEC-Q101-001	Human body model	HBM	C = 100 pF, R = 1.5 kΩ	H1B	>500 to ≤ 1k	V
	Machine model	MM	C = 200 pF, R = 0 Ω	M1B	>50 to ≤ 100	V

Note2: Measurement circuit

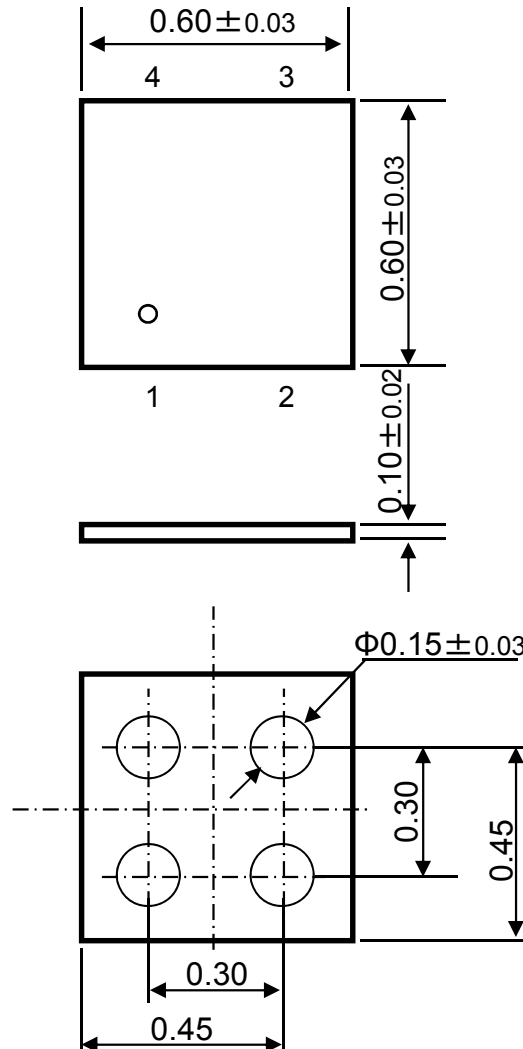




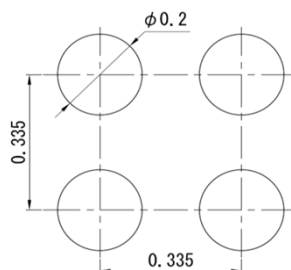


■ ALGA004-W-0606-RA01

Unit: mm



■ Land Pattern (Reference)



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